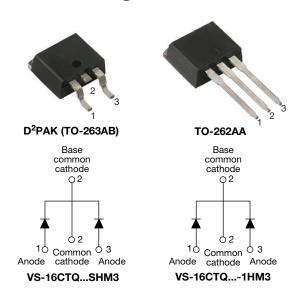


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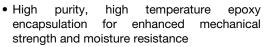
High Performance Schottky Rectifier, 2 x 8 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 x 8 A						
V_{R}	60 V to 100 V					
V _F at I _F	0.58 V					
I _{RM}	7.0 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	7.5 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop





FREE

- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	16	Α					
V _{RRM}		60 to 100	V					
I _{FSM}	$t_p = 5 \mu s sine$	850	Α					
V _F	8 A _{pk} , T _J = 125 °C (per leg)	0.58	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-16CTQ060SHM3 VS-16CTQ080SHM3 VS-16CTQ100SHM3 VS-16CTQ100-1HM3 VS-16CTQ100-1HM3								
Maximum DC reverse voltage	V_R	60	80	100	W			
Maximum working peak reverse voltage	V_{RWM}	00	00	100	V			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS
Maximum average forward current per leg	1	50 % duty cycle at T _C = 148 °C	rootongular wayoform	8	۸
See fig. 5 per device	I _{F(AV)}	50 % duty cycle at 1 _C = 148 C	16	Α	
Maximum peak one cycle non-repetitive surge current per leg	1	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		850	Α
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	275	A	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim		0.50	Α



VS-16CTQ...SHM3, VS-16CTQ...-1HM3 Series

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop per leg See fig. 1		8 A	T _{.1} = 25 °C	0.72				
	V (1)	16 A	- IJ=25 C	0.88	V			
	V _{FM} ⁽¹⁾	8 A	T 105 °C	0.58				
		16 A	- T _J = 125 °C	0.69				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	\/	0.55	mA			
See fig. 2		T _J = 125 °C	V _R = rated V _R	7.0				
Threshold voltage	V _{F(TO)}	T T		0.415	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		11.07	mΩ			
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	500	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}	Stg		°C			
Maximum thermal resistance, junction to case per leg		D	DC operation	3.25				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.63	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf \cdot in)			
Maddan da tan			Case style D ² PAK (TO-263AB)	16CTC	QSH			
Marking device			Case style TO-262AA	16CTC)1H			

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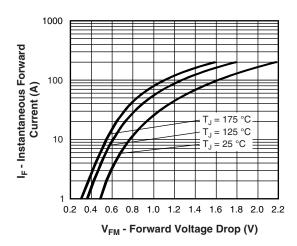


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

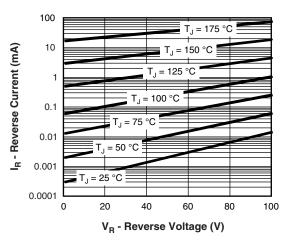


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

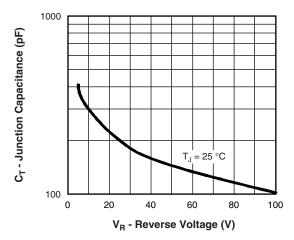


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

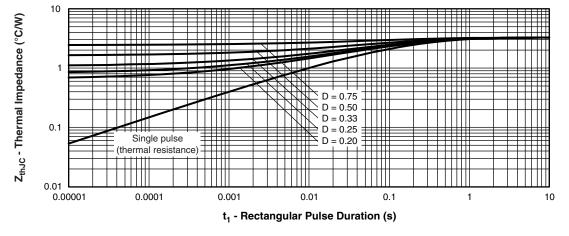


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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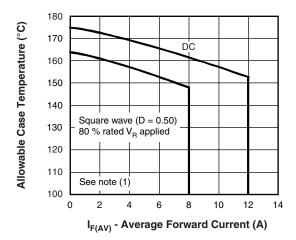


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

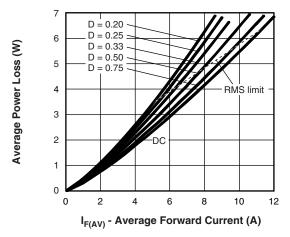


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

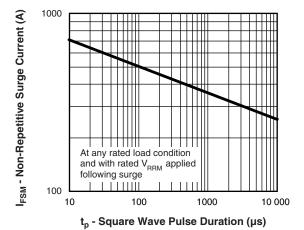


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

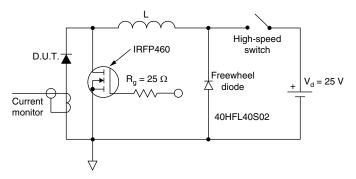


Fig. 8 - Unclamped Inductive Test Circuit

Note

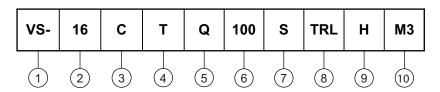
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R applied

VS-16CTQ...SHM3, VS-16CTQ...-1HM3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (16 A)

3 - Circuit configuration: C = Common cathode

4 - T = TO-220

5 - Schottky "Q" series

060 = 60 V

Voltage ratings

080 = 80 V100 = 100 V

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

| 10 | - M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATI	ON		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-16CTQ060SHM3	50	1000	Antistatic plastic tubes
VS-16CTQ060STRRHM3	800	800	13" diameter reel
VS-16CTQ060STRLHM3	800	800	13" diameter reel
VS-16CTQ060-1HM3	50	1000	Antistatic plastic tubes
VS-16CTQ080SHM3	50	1000	Antistatic plastic tubes
VS-16CTQ080STRRHM3	800	800	13" diameter reel
VS-16CTQ080STRLHM3	800	800	13" diameter reel
VS-16CTQ080-1HM3	50	1000	Antistatic plastic tubes
VS-16CTQ100SHM3	50	1000	Antistatic plastic tubes
VS-16CTQ100STRRHM3	800	800	13" diameter reel
VS-16CTQ100STRLHM3	800	800	13" diameter reel
VS-16CTQ100-1HM3	50	1000	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046				
Dimensions	TO-262AA	www.vishay.com/doc?95419				
Doub woulding information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?95032				
SPICE model		www.vishay.com/doc?95279				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	ES SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

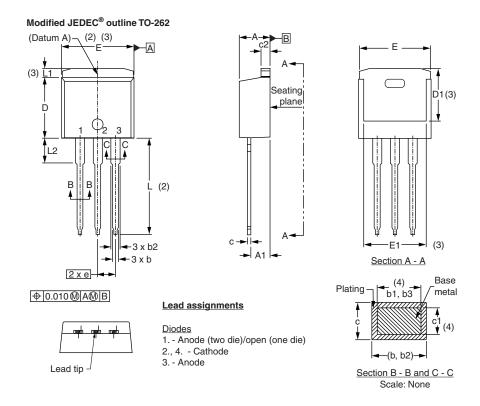
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES			
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.10	D BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019 1 Document Number: 95419



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